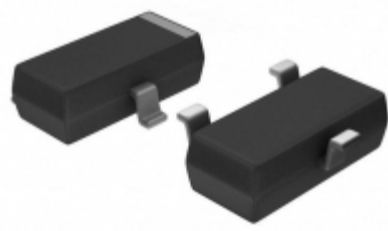


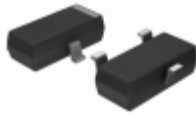
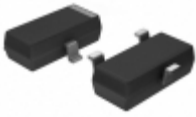

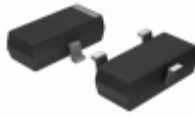




	<h2 style="color: red;">FJV4109RMTF</h2>
	Hersteller-Teilenummer: FJV4109RMTF
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: TRANS PREBIAS PNP 200MW SOT23-3
	Datenblätter: <ul style="list-style-type: none">  1.FJV4109RMTF.pdf  2.FJV4109RMTF.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 127350 pcs Stock Available.
	Liefern von: Hong Kong
	Versandweg: DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV4109RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS PNP 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	127350 pcs Stock
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	PNP - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	40V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 1mA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	100 @ 1mA, 5V
Frequenz - Übergang	200MHz
Verpackung	Tape & Reel (TR)
Widerstand - Basis (R1)	4.7 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)


FJV4109RMTF ist neu im Original, Suche FJV4109RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV4109RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV4109RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV4108RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4108RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4107RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4111RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>
 <p>FJV4111RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4110RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4107RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4106RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>

heiße Teile

Mehr

 FJV3108RMTF	 FJV3108RMTF	 FJV3109R	D FJV3109RMTF	 FJV3109RMTF
 FJV3110RMTF	 FJV3110RMTF	D FJV3111RMTF	 FJV3111RMTF	 FJV3112RMTF
 FJV3112RMTF	 FJV3113RMTF	 FJV3113RMTF	 FJV3114RMTF	 FJV3114RMTF
D FJV3115RMTF	 FJV3115RMTF	 FJV4101RMTF	 FJV4101RMTF	 FJV4102RLIMTF
 FJV4102RMTF	 FJV4102RMTF	 FJV4103RMTF	 FJV4103RMTF	 FJV4104RMTF
 FJV4104RMTF	 FJV4105RMTF	D FJV4105RMTF	 FJV4106RMTF	 FJV4106RMTF
 FJV4107RMTF	D FJV4107RMTF	 FJV4108RMTF	 FJV4108RMTF	 FJV4109RMTF
 FJV4110RMTF	 FJV4110RMTF	 FJV4111RMTF	 FJV4111RMTF	 FJV4112RMTF
 FJV4112RMTF	 FJV4113RMTF	 FJV4113RMTF	D FJV4114RMTF	 FJV4114RMTF
 FJV42MTF	 FJV42MTF	 FJV992EMTF	 FJV992PMTF	 FJV992PMTF

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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